

# VND10B DOUBLE CHANNEL HIGH SIDE SMART POWER SOLID STATE RELAY

#### **Table 1. General Features**

| Туре   | V <sub>DSS</sub> | R <sub>DS(on)</sub> | I <sub>n</sub> (1) | Vcc  |
|--------|------------------|---------------------|--------------------|------|
| VND10B | 40 V             | 0.1 Ω               | 3.4 A              | 26 V |

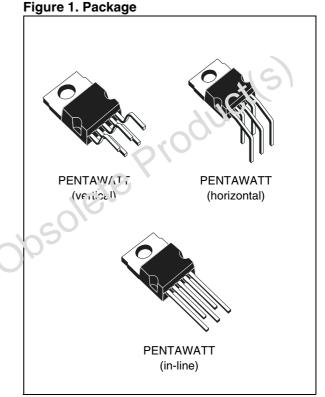
Note: 1. In= Nominal current according to ISO definition for high side automotive switch. The Nominal Current is the current at  $T_c = 85$  °C for battery voltage of 13V which produces a voltage drop of 0.5 V.

- OUTPUT CURRENT (CONTINUOUS): 14 A @ T<sub>c</sub>=85°C PER CHANNEL
- 5V LOGIC LEVEL COMPATIBLE INPUT
- THERMAL SHUT-DOWN
- UNDER VOLTAGE PROTECTION
- OPEN DRAIN DIAGNOSTIC OUTPUT
- INDUCTIVE LOAD FAST DEMAGNETIZATION
- VERY LOW STAND-BY POWER DISSIPATION

#### DESCRIPTION

The VND10B is a monolithic device made using STMicroelectronics V.Power Technology, intended for driving resistive or inductive loads with one side grounded. This device has two channels, and a common diagnostic. Built-in thermal shut down protects the chip from over temperature and short circuit.

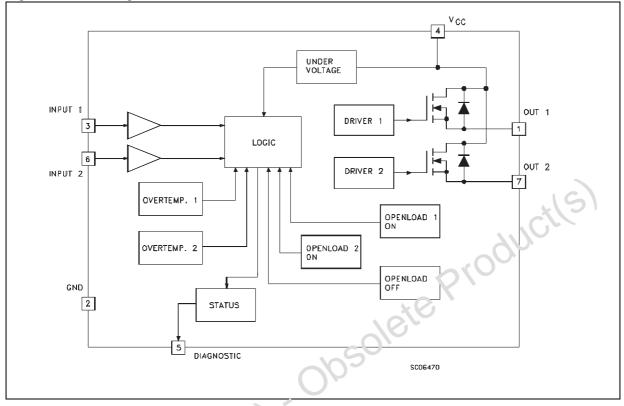
The s atus output provides an indication of open load in on state, open load in off state, overtemperature conditions and stuck-on to  $V_{CC}$ .



| Tahla | 2  | Order | Codes |
|-------|----|-------|-------|
| rable | ۷. | Order | Codes |

| Package           | Tube         | Tape and Reel |
|-------------------|--------------|---------------|
| PENTAWATT Vert.   | VND10B       | -             |
| PENTAWATT Hor.    | VND10B(011Y) | -             |
| PENTAWATT In line | VND10B(012Y) | _             |

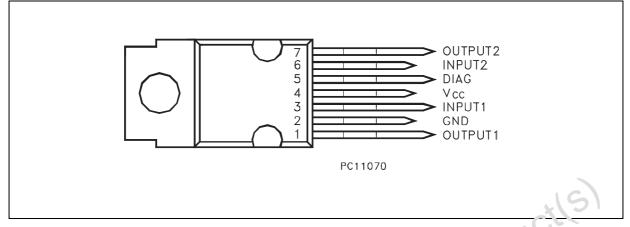
# Figure 2. Block Diagram



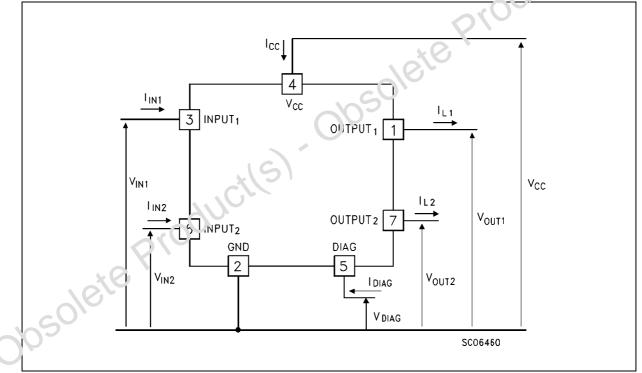
# Table 3. Absolute Maximum Ratings 🕤

| Symbol                 | Parameter   | Value      | Unit |
|------------------------|---|------------|------|
| V <sub>(BR)DSS</sub>   | Drain-Source Brack town Voltage                   | 40         | V    |
| IOUT                   | Output Cu rent (cont.) at T <sub>c</sub> = 85 °C  | 14         | А    |
| I <sub>OUT</sub> (RMS) | RMS Cutput Current at T <sub>c</sub> = 85 °C      | 14         | А    |
| I <sub>R</sub>         | F.everse Output Current at T <sub>c</sub> = 85 °C | -14        | А    |
| Lin                    | Input Current                                     | ±10        | mA   |
| - /cc                  | Reverse Supply Voltage                            | -4         | V    |
| ISTAT                  | Status Current                                    | ±10        | mA   |
| V <sub>ESD</sub>       | Electrostatic Discharge (1.5 kΩ; 100 pF)          | 2000       | V    |
| P <sub>tot</sub>       | Power Dissipation at $T_c = 25 \ ^{\circ}C$       | 75         | W    |
| Тj                     | Junction Operating Temperature                    | -40 to 150 | °C   |
| T <sub>stg</sub>       | Storage Temperature                               | -55 to 150 | °C   |

# Figure 3. Connection Diagram



# Figure 4. Current and Voltage Conventions



## Table 4. Thermal Data

| Symbol                | Parameter                           |     | Value | Unit |
|-----------------------|-------------------------------------|-----|-------|------|
| R <sub>thj-case</sub> | Thermal Resistance Junction-case    | Max | 1.65  | °C/W |
| R <sub>thj-amb</sub>  | Thermal Resistance Junction-ambient | Max | 60    | °C/W |

| <u> </u> | ) | 1 | 1 |
|----------|---|---|---|
|          |   |   |   |

#### **ELECTRICAL CHARACTERISTICS**

(8 < V\_{CC} < 16 V; -40  $\leq$  T\_j  $\leq$  125 °C unless otherwise specified)

### Table 5. Power

| Symbol               | Parameter                           | Test Conditions  | Min.  | Тур. | Max. | Unit    |
|----------------------|-------------------------------------|--|-------|------|------|---------|
| V <sub>CC</sub>      | Supply Voltage                      |  | 6     | 13   | 26   | V       |
| In <sup>(2)</sup>    | Nominal Current                     | $T_{c} = 85 \ ^{\circ}C; \ V_{DS(on)} \leq 0.5; \ V_{CC} = 13 \ V$   | 3.4   |      | 5.2  | А       |
| Ron                  | On State Resistance                 | $I_{OUT} = I_n; V_{CC} = 13 V; T_j = 25 \ ^{\circ}C$                 | 0.065 |      | 0.1  | Ω       |
| I <sub>S</sub>       | Supply Current                      | Off State; $T_j = 25 \text{ °C}$ ; $V_{CC} = 13 \text{ V}$           |       | 35   | 100  | μA      |
| V <sub>DS(MAX)</sub> | Maximum Voltage Drop                | $I_{OUT} = 13 \text{ A}; T_j = 85 \text{ °C}; V_{CC} = 13 \text{ V}$ | 1.2   |      | 2    | V       |
| Ri                   | Output to GND internal<br>Impedance | T <sub>j</sub> = 25 °C   | 5     | 10   | 20   | δ<br>KΩ |

Note: 2. In= Nominal current according to ISO definition for high side automotive switch. The Nominal Current is the current at T<sub>c</sub> = 85 °C for battery voltage of 13V which produces a voltage drop of 0.5 V.

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#### Table 6. Switching

| Symbol                            | Parameter                                | Test Conditions          | Min.  | Тур. | Max. | Unit |
|-----------------------------------|--|--------------------------|-------|------|------|------|
| t <sub>d(on)</sub> <sup>(3)</sup> | Turn-on Delay Time Of<br>Output Current  | R <sub>OUT</sub> = 2.7 Ω | 5     | 35   | 200  | μs   |
| $t_r^{(3)}$                       | Rise Time Of Output<br>Current           | R <sub>OUT</sub> = 2.7 Ω | 28    | 110  | 360  | μs   |
| $t_{d(off)}^{(3)}$                | Turn-off Delay Time Of<br>Output Current | R <sub>OUT</sub> = 2.7 Ω | 10    | 140  | 500  | μs   |
| $t_{f}^{(3)}$                     | Fall Time Of Output<br>Current           | Rou : - 2.7 Ω            | 28    | 75   | 360  | μs   |
| (di/dt) <sub>on</sub>             | Turn-on Current Slope                    | R <sub>OUT</sub> = 2.7 Ω | 0.003 |      | 0.1  | A/µs |
| (di/dt) <sub>off</sub>            | Turn-off Current הארוה                   | R <sub>OUT</sub> = 2.7 Ω | 0.005 |      | 0.1  | A/µs |

Note: 3. See Switching Time Woveforms.

## Table 7. Logic input

| Symbol               | Parameter                | Test Conditions                                     | Min. | Тур.      | Max.   | Unit   |
|----------------------|--------------------------|---|------|-----------|--------|--------|
| - Vj-                | Input Low Level Voltage  |   |      |           | 1.5    | V      |
| VIH                  | Input High Level Voltage |   | 3.5  |           | Note 4 | V      |
| V <sub>I(hyst)</sub> | Input Hysteresis Voltage |   | 0.2  | 0.9       | 1.5    | V      |
| l <sub>IN</sub>      | Input Current            | $V_{IN} = 5 V; T_j = 25 °C$                         |      | 30        | 100    | μA     |
| VICL                 | Input Clamp Voltage      | l <sub>IN</sub> = 10 mA<br>l <sub>IN</sub> = -10 mA | 5    | 6<br>–0.7 | 7      | V<br>V |

Note: 4. The V<sub>IH</sub> is internally clamped at 6V about. It is possible to connect this pin to an higher voltage via an external resistor calculated to not exceed 10 mA at the input pin.

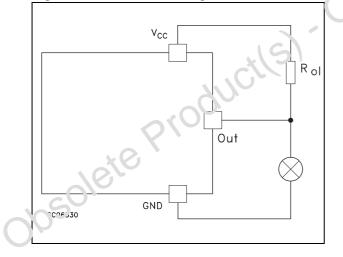
## ELECTRICAL CHARACTERISTICS (cont'd)

| Symbol                         | Parameter                     | Test Conditions   | Min. | Тур.     | Max. | Unit   |
|--------------------------------|-------------------------------|---|------|----------|------|--------|
| V <sub>STAT</sub>              | Status Voltage Output Low     | I <sub>STAT</sub> = 1.6 mA                                |      |          | 0.4  | V      |
| V <sub>USD</sub>               | Under Voltage Shut Down       |   | 3.5  | 4.5      | 6    | V      |
| V <sub>SCL</sub>               | Status Clamp Voltage          | $I_{STAT} = 10 \text{ mA}$<br>$I_{STAT} = -10 \text{ mA}$ | 5    | 6<br>0.7 | 7    | V<br>V |
| T <sub>TSD</sub>               | Thermal Shut-down Temperature |   | 140  | 160      | 180  | °C     |
| T <sub>SD(hyst.)</sub>         | Thermal Shut-down Hysteresis  |   |      |          | 50   | °C     |
| T <sub>R</sub>                 | Reset Temperature             |   | 125  |          | 10   | D C    |
| V <sub>OL</sub> <sup>(5)</sup> | Open Voltage Level            | Off-State   | 2.5  | 4        | 5    | V      |
| I <sub>OL</sub>                | Open Load Current Level       |   | 0.6  | 0.9      | 1.4  | Α      |
| t <sub>povl</sub> (6)          | Status Delay                  |   | 20   | 5        | 10   | μs     |
| t <sub>pol</sub> (6)           | Status Delay                  |   | 50   | 500      | 2500 | μs     |

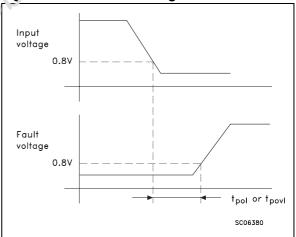
#### **Table 8. Protection and Diagnostics**

Note: 5.  $I_{OL(off)} = (V_{CC} - V_{OL})/R_{OL}$  (see figure 5) 6.  $t_{povl} t_{pol}$ : ISO definition (see figure 6).

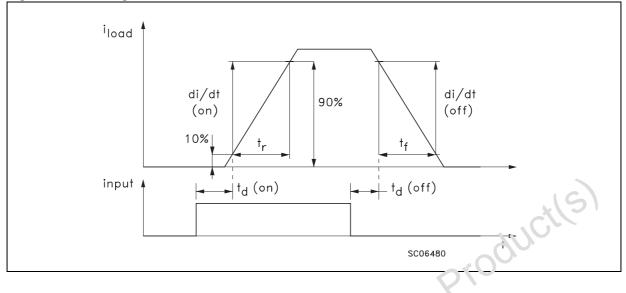
## Figure 5. Note 5 relevant figure



## Figure 6. Note 6 relevant figure



#### Figure 7. Switching Time Waveforms



#### FUNCTIONAL DESCRIPTION

The device has a common diagnostic output for both channels which indicates open load in onstate, open load in off-state, over temperature conditions and stuck-on to  $V_{CC}$ .

From the falling edge of the input signal, the status output, initially low to signal a fault condition (overtemperature or open load on-state), vil go back to a high state with a different aplay in case of overtemperature (tpov) and in case of open open load (tpol) respectively. היוב feature allows to discriminate the nature citie detected fault. To protect the device against short circuit and over current condition, the thermal protection turns the integrated Power MOS off at a minimum junction temperature of 140 °C. When this temperature returns to 125 °C the switch is automatically turned on again in short circuit the protection reacts with virtualy no delay, the sensor (one for each channel) being located inside each of the two Power MOS areas. This positioning allows the device to operate with one channel in automatic thermal cycling and the other one on a normal load. An internal function of the devices ensures the fast demagnetization of inductive loads with a typical voltage (V<sub>demag</sub>) of -18V. This function allows to greatly reduces the power dissipation according to the formula:

 $P_{dem} = 0.5 \bullet L_{load} \bullet (I_{load})^2 \bullet [(V_{CC} + V_{demag}) / V_{demag}] \bullet f$ 

where f = switching frequency and

V<sub>demag</sub> = demagnetization voltage

The maximum inductance which causes the chip temperature to reach the shut-down temperature in a specified thermal environment is a function of the load current for a fixed  $V_{CC}$ ,  $V_{demag}$  and f according to the above formula. In this device if the GND pin is disconnected, with  $V_{CC}$  not exceeding 16V, both channel will switch off.

# PROTECTING THE DEVICE AGAINST REVERSE BATTERY

The simplest way to protect the device against a continuous reverse battery voltage (-26V) is to insert a Schottky diode between pin 1(GND) and ground, as shown in the typical application circuit (Figure 9).

The consequences of the voltage drop across this diode are as follows:

- If the input is pulled to power GND, a negative voltage of -V<sub>f</sub> is seen by the device. (V<sub>IL</sub>, V<sub>IH</sub> thresholds and V<sub>STAT</sub> are increased by V<sub>f</sub> with respect to power GND).
- The undervoltage shutdown level is increased by V<sub>f</sub>.

If there is no need for the control unit to handle external analog signals referred to the power GND, the best approach is to connect the reference potential of the control unit to node [1] (see application circuit in Figure 10), which becomes the common signal GND for the whole control board avoiding shift of  $V_{IH}$ ,  $V_{IL}$  and  $V_{STAT}$ . This solution allows the use of a standard diode.

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## Table 9. Truth Table

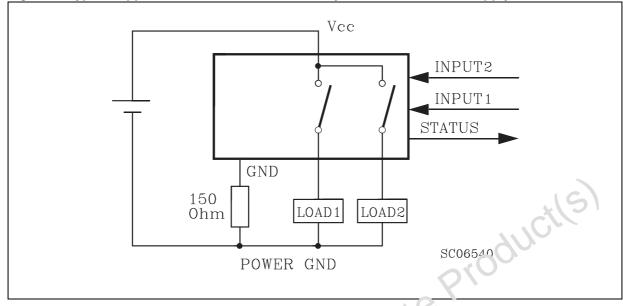
|   |           | Input 1          | Input 2          | Output 1         | Output 2         | Diagnostic            |  |
|---|-----------|------------------|------------------|------------------|------------------|-----------------------|--|
| Normal Operation  |           | L<br>H<br>L<br>H | L<br>H<br>H<br>L | L<br>H<br>L<br>H | L<br>H<br>H<br>L | нтт                   |  |
| Under voltage   |           | Х                | Х                | L                | L                | Н                     |  |
| Thermal Shutdown  | Channel 1 | Н                | Х                | L                | Х                | L                     |  |
|   | Channel 2 | Х                | Н                | Х                | L                | L                     |  |
| Open Load   | Channel 1 | H<br>L           | X<br>L           | H<br>L           | X<br>L           | L<br>L <sup>(7)</sup> |  |
|   | Channel 2 | X<br>L           | H<br>L           | X<br>L           | H                |                       |  |
| Output Shorted to V <sub>CC</sub>                               | Channel 1 | ΗL               | X<br>L           | H<br>H           | UČO.             | L                     |  |
|   | Channel 2 | X<br>L           | H<br>L           | X<br>L           | Н                | LL                    |  |
| Note: 7. With additional external resistor. Figure 8. Waveforms |           |                  |                  |                  |                  |                       |  |
|   | -         |                  |                  |                  |                  |                       |  |

# Figure 8. Waveforms

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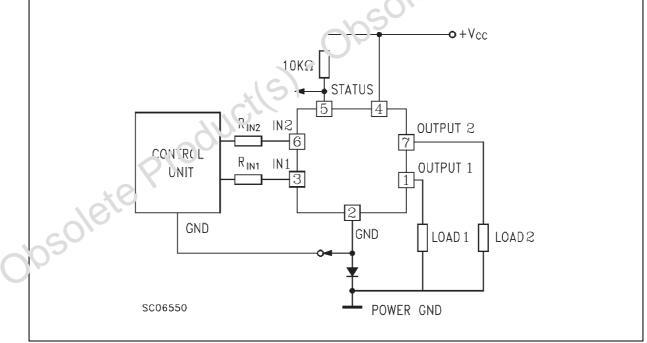
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|   | INPUT   | NOR MAL<br>OPERATION              | INPUT<br>STATUS<br>SWITCH On<br>Off                         |         | OPEN LOAD  |
|---|---|-----------------------------------|---|---------|--|
| C | INPUT   | UNDER<br>VOLTAGE                  | INPUT<br>STATUS<br>SWITCH <sup>On</sup><br><sup>I</sup> OUT |         | THERMAL<br>SHUTDOWN<br>- 140 <sup>o</sup> C<br>–125 <sup>o</sup> C |
|   | INPUT<br>LOAD<br>CURRENT<br>DIAG<br>SWITCH On Off | OUTPUT SHOR<br>TO V <sub>CC</sub> | TED   | SC06590 |  |









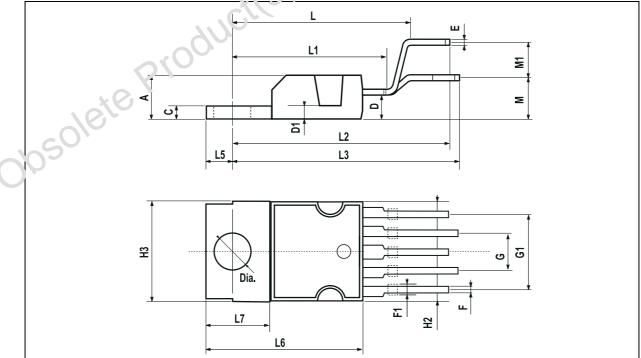
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## PACKAGE MECHANICAL

| Symbol | millimeters |       |      |  |
|--------|-------------|-------|------|--|
|        | Min         | Тур   | Мах  |  |
| А      |             |       | 4.8  |  |
| С      |             |       | 1.37 |  |
| D      | 2.4         |       | 2.8  |  |
| D1     | 1.2         |       | 1.35 |  |
| E      | 0.35        |       | 0.55 |  |
| F      | 0.8         |       | 1.05 |  |
| F1     | 1           |       | 1.4  |  |
| G      | 3.2         | 3.4   | Ĵ.Ł  |  |
| G1     | 6.6         | 6.8   | 7    |  |
| H2     |             |       | 10.4 |  |
| H3     | 10.05       |       | 10.4 |  |
| L2     | 23.05       | 23.4  | 23.8 |  |
| L3     | 25.3        | 25.65 | 26.1 |  |
| L5     | 2.6         | 0     | 3    |  |
| L6     | 15.1        | S     | 15.8 |  |
| L7     | 6           | 70-   | 6.6  |  |
| Dia.   | 3.65        |       | 3.85 |  |

## Table 10. PENTAWATT (vertical) Mechanical Data

## Figure 11. PENTAWATT (vertical) Pacing Dimensions

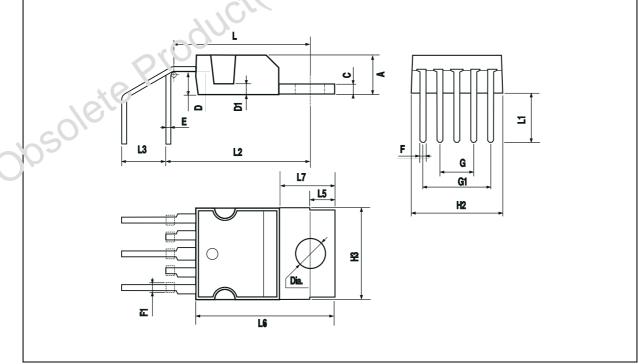


Note: Drawing is not to scale.

| Symbol | millimeters |         |      |
|--------|-------------|---------|------|
|        | Min         | Тур     | Мах  |
| А      |             |         | 4.8  |
| С      |             |         | 1.37 |
| D      | 2.4         |         | 2.8  |
| D1     | 1.2         |         | 1.35 |
| E      | 0.35        |         | 0.55 |
| F      | 0.8         |         | 1.05 |
| F1     | 1           |         | 1.4  |
| G      | 3.2         | 3.4     | 3.6  |
| G1     | 6.6         | 6.8     | z (5 |
| H2     |             |         | 10.4 |
| H3     |             |         | 10.4 |
| L      | 14.2        | 14.2 15 |      |
| L1     | 5.7 6.2     |         | 6.2  |
| L2     | 14.6        |         | 15.2 |
| L3     | 3.5         |         | 4.1  |
| L5     | 2.6         |         | 3    |
| L6     | 15.1        | 5       | 15.8 |
| L7     | 6           | NV      | 6.6  |
| Dia.   | 3.65        |         | 3.85 |

## Table 11. PENTAWATT (horizontal) Mechanical Data

# Figure 12. PENTAWATT (horizontal) Package Dimensions

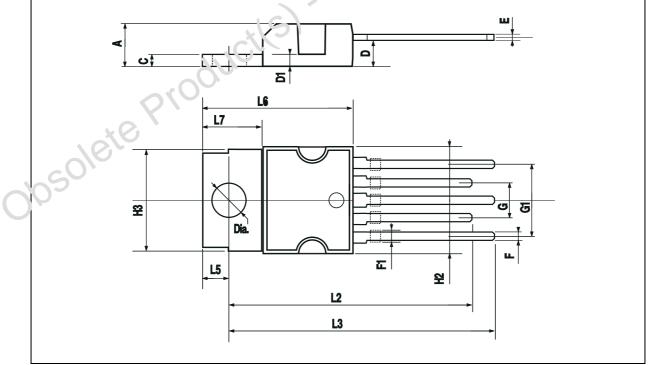


Note: Drawing is not to scale.

| Symbol | millimeters |       |      |  |
|--------|-------------|-------|------|--|
|        | Min         | Тур   | Мах  |  |
| A      |             |       | 4.8  |  |
| С      |             |       | 1.37 |  |
| D      | 2.4         |       | 2.8  |  |
| D1     | 1.2         |       | 1.35 |  |
| E      | 0.35        |       | 0.55 |  |
| F      | 0.8         |       | 1.05 |  |
| F1     | 1           |       | 1.4  |  |
| G      | 3.2         | 3.4   | 3.6  |  |
| G1     | 6.6         | 6.8   | 75   |  |
| H2     |             | 10.   |      |  |
| H3     | 10.05       | 10.05 |      |  |
| L2     | 23.05       | 23.4  | 23.8 |  |
| L3     | 25.3        | 25.65 | 26.1 |  |
| L5     | 2.6         |       | 3    |  |
| L6     | 15.1        |       | 15.8 |  |
| L7     | 6           |       | 6.6  |  |
| Dia.   | 3.65        | 5     | 3.85 |  |

Table 12. PENTAWATT (in-line) Mechanical Data

## Figure 13. PENTAWATT (in-line) Package Dimensions



Note: Drawing is not to scale.



### **REVISION HISTORY**

#### Table 13. Revision History

| Date           | Revision | Description of Changes                |
|----------------|----------|---------------------------------------|
| September-1994 | 1        | First Issue                           |
| 18-June-2004   | 2        | Stylesheet update. No content change. |

obsolete Product(s). Obsolete Product(s)

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